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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Complete if Known				
Application Number	10/510,916			
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First Named Inventor	Shinichi ISHIBASHI			
Art Unit	1795			
Examiner Name	Stephen D. Rosasco			
Attorney Docket Number	Q84137			

U.S. PATENT DOCUMENTS						
Examiner Cite No. 1	Cita	Document	Number	Publication Date		
		Number	Kind Code ² (if known)	MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	

FOREIGN PATENT DOCUMENTS							
Examiner Cite	Foreign Patent Document			Publication Date	Name of Patentee or		
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NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.			
		M. TAKAHASHI, et al: "Tantalum nitride films for the absorber material of reflective-type EUVL mask", Proceedings of the Spie, The International Society for Optical Engineering Spie-Int. Soc. Opt. Eng USA, 2001, pages 760-770, Vol. 4343.			
		SHINJI TSUBOI, et al., Recent progress in 1Xx-ray mask technology: Feasibility Study using ASET-NIST format TaXN x-ray masks with 100 nm rule 4 Gbit dynamic random access memory test patterns, 2001 American Society, pgs. 2416-2422.			
		KENNETH RACETTE, et al., Sputter deposition and annealing of Ta, TaSI _X and TaB _X composite films and their application in next generation lithography masks, 2000 American Vacuum Society, pgs. 1119-1124.			

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Examiner Signature	Date Considered	

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